



Welcome to [E-XFL.COM](#)

What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, I ² C, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	45
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	48K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5604camlh6r

- ⁶ CAN0, CAN1 are available. CAN2, CAN3, CAN4 and CAN5 are not available.
- ⁷ CAN0, CAN1 and CAN2 are available. CAN3, CAN4 and CAN5 are not available.
- ⁸ I/O count based on multiplexing with peripherals
- ⁹ All LQFP64 information is indicative and must be confirmed during silicon validation.
- ¹⁰ LBGA208 available only as development package for Nexus2+

2 Block diagram

Figure 1 shows a top-level block diagram of the MPC5604B/C device series.

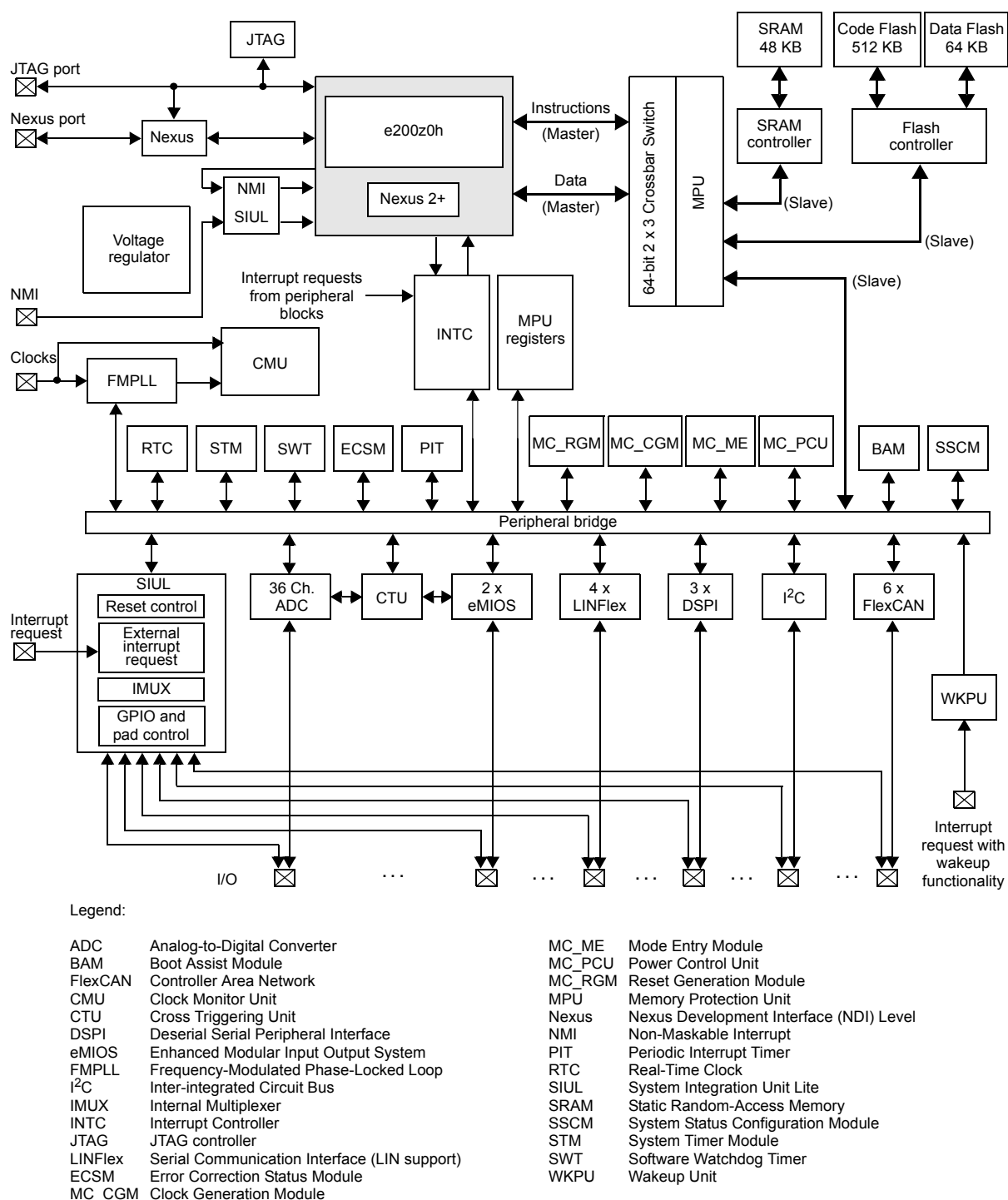
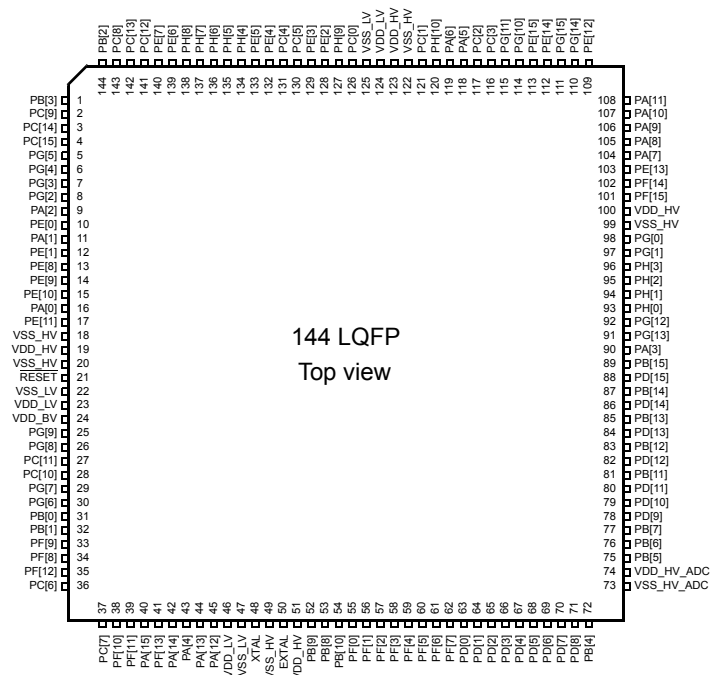


Figure 1. MPC5604B/C block diagram



Note:

Availability of port pin alternate functions depends on product selection.

Figure 5. LQFP 144-pin configuration

3.5 System pins

The system pins are listed in [Table 5](#).

Table 5. System pin descriptions

System pin	Function	I/O direction	Pad type	RESET configuration	Pin number			
					64 LQFP ¹	100 LQFP	144 LQFP	208 MAPBGA ²
RESET	Bidirectional reset with Schmitt-Trigger characteristics and noise filter.	I/O	M	Input, weak pull-up only after PHASE2	9	17	21	J1
EXTAL	Analog output of the oscillator amplifier circuit, when the oscillator is not in bypass mode. Analog input for the clock generator when the oscillator is in bypass mode. ³	I/O	X	Tristate	27	36	50	N8
XTAL	Analog input of the oscillator amplifier circuit. Needs to be grounded if oscillator is used in bypass mode. ³	I	X	Tristate	25	34	48	P8

¹ Pin numbers apply to both the MPC560xB and MPC560xC packages.

² 208 MAPBGA available only as development package for Nexus2+

³ See the relevant section of the datasheet

3.6 Functional ports

The functional port pins are listed in [Table 6](#).

Table 6. Functional port pin descriptions

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PA[0]	PCR[0]	AF0 AF1 AF2 AF3 —	GPIO[0] E0UC[0] CLKOUT — WKPU[19] ⁴	SIUL eMIOS_0 CGL — WKPU	I/O I/O O — I	M	Tristate	5	5	12	16	G4
PA[1]	PCR[1]	AF0 AF1 AF2 AF3 — —	GPIO[1] E0UC[1] — — NMI ⁵ WKPU[2] ⁴	SIUL eMIOS_0 — — WKPU WKPU	I/O I/O — — I I	S	Tristate	4	4	7	11	F3

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PB[3]	PCR[19]	AF0 AF1 AF2 AF3 — —	GPIO[19] — SCL — WKPU[11] ⁴ LIN0RX	SIUL — I2C_0 — WKPU LINFlex_0	I/O — I/O — I I	S	Tristate	1	1	1	1	C3
PB[4]	PCR[20]	AF0 AF1 AF2 AF3 —	GPIO[20] — — — GPIO[0]	SIUL — — — ADC	I — — — I	I	Tristate	32	32	50	72	T16
PB[5]	PCR[21]	AF0 AF1 AF2 AF3 —	GPIO[21] — — — GPIO[1]	SIUL — — — ADC	I — — — I	I	Tristate	35	—	53	75	R16
PB[6]	PCR[22]	AF0 AF1 AF2 AF3 —	GPIO[22] — — — GPIO[2]	SIUL — — — ADC	I — — — I	I	Tristate	36	—	54	76	P15
PB[7]	PCR[23]	AF0 AF1 AF2 AF3 —	GPIO[23] — — — GPIO[3]	SIUL — — — ADC	I — — — I	I	Tristate	37	35	55	77	P16
PB[8]	PCR[24]	AF0 AF1 AF2 AF3 — —	GPIO[24] — — — ANS[0] OSC32K_XTAL ⁷	SIUL — — — ADC SXOSC	I — — — I I/O	I	Tristate	30	30	39	53	R9
PB[9]	PCR[25]	AF0 AF1 AF2 AF3 — —	GPIO[25] — — — ANS[1] OSC32K_EXTAL ⁷	SIUL — — — ADC SXOSC	I — — — I I/O	I	Tristate	29	29	38	52	T9

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PB[10]	PCR[26]	AF0 AF1 AF2 AF3 — —	GPIO[26] — — — ANS[2] WKPU[8] ⁴	SIUL — — — ADC WKPU	I/O — — — I I	J	Tristate	31	31	40	54	P9
PB[11] ⁸	PCR[27]	AF0 AF1 AF2 AF3 —	GPIO[27] E0UC[3] — CS0_0 ANS[3]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — I/O I	J	Tristate	38	36	59	81	N13
PB[12]	PCR[28]	AF0 AF1 AF2 AF3 —	GPIO[28] E0UC[4] — CS1_0 ANX[0]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	39	—	61	83	M16
PB[13]	PCR[29]	AF0 AF1 AF2 AF3 —	GPIO[29] E0UC[5] — CS2_0 ANX[1]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	40	—	63	85	M13
PB[14]	PCR[30]	AF0 AF1 AF2 AF3 —	GPIO[30] E0UC[6] — CS3_0 ANX[2]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	41	37	65	87	L16
PB[15]	PCR[31]	AF0 AF1 AF2 AF3 —	GPIO[31] E0UC[7] — CS4_0 ANX[3]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	42	38	67	89	L13
PC[0] ⁹	PCR[32]	AF0 AF1 AF2 AF3	GPIO[32] — TDI —	SIUL — JTAGC —	I/O — I —	M	Input, weak pull-up	59	59	87	126	A8
PC[1] ⁹	PCR[33]	AF0 AF1 AF2 AF3	GPIO[33] — TDO ¹⁰ —	SIUL — JTAGC —	I/O — O —	M	Tristate	54	54	82	121	C9

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PC[9]	PCR[41]	AF0 AF1 AF2 AF3 — —	GPIO[41] — — — LIN2RX WKPU[13] ⁴	SIUL — — — LINFlex_2 WKPU	I/O — — — I I	S	Tristate	2	2	2	2	B1
PC[10]	PCR[42]	AF0 AF1 AF2 AF3	GPIO[42] CAN1TX CAN4TX ¹¹ MA[1]	SIUL FlexCAN_1 FlexCAN_4 ADC	I/O O O O	M	Tristate	13	13	22	28	M3
PC[11]	PCR[43]	AF0 AF1 AF2 AF3 — — —	GPIO[43] — — — CAN1RX CAN4RX ¹¹ WKPU[5] ⁴	SIUL — — — FlexCAN_1 FlexCAN_4 WKPU	I/O — — — I I I	S	Tristate	—	—	21	27	M4
PC[12]	PCR[44]	AF0 AF1 AF2 AF3 —	GPIO[44] E0UC[12] — — SIN_2	SIUL eMIOS_0 — — DSPI_2	I/O I/O — — I	M	Tristate	—	—	97	141	B4
PC[13]	PCR[45]	AF0 AF1 AF2 AF3	GPIO[45] E0UC[13] SOUT_2 —	SIUL eMIOS_0 DSPI_2 —	I/O I/O O —	S	Tristate	—	—	98	142	A2
PC[14]	PCR[46]	AF0 AF1 AF2 AF3 —	GPIO[46] E0UC[14] SCK_2 — EIRQ[8]	SIUL eMIOS_0 DSPI_2 — SIUL	I/O I/O I/O — I	S	Tristate	—	—	3	3	C1
PC[15]	PCR[47]	AF0 AF1 AF2 AF3	GPIO[47] E0UC[15] CS0_2 —	SIUL eMIOS_0 DSPI_2 —	I/O I/O I/O —	M	Tristate	—	—	4	4	D3
PD[0]	PCR[48]	AF0 AF1 AF2 AF3 —	GPIO[48] — — — GPI[4]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	41	63	P12

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PE[1]	PCR[65]	AF0 AF1 AF2 AF3	GPIO[65] E0UC[17] CAN5TX ¹¹ —	SIUL eMIOS_0 FlexCAN_5 —	I/O I/O O —	M	Tristate	—	—	8	12	F4
PE[2]	PCR[66]	AF0 AF1 AF2 AF3 —	GPIO[66] E0UC[18] — — SIN_1	SIUL eMIOS_0 — — DSPI_1	I/O I/O — — I	M	Tristate	—	—	89	128	D7
PE[3]	PCR[67]	AF0 AF1 AF2 AF3	GPIO[67] E0UC[19] SOUT_1 —	SIUL eMIOS_0 DSPI_1 —	I/O I/O O —	M	Tristate	—	—	90	129	C7
PE[4]	PCR[68]	AF0 AF1 AF2 AF3 —	GPIO[68] E0UC[20] SCK_1 — EIRQ[9]	SIUL eMIOS_0 DSPI_1 — SIUL	I/O I/O I/O — I	M	Tristate	—	—	93	132	D6
PE[5]	PCR[69]	AF0 AF1 AF2 AF3	GPIO[69] E0UC[21] CS0_1 MA[2]	SIUL eMIOS_0 DSPI_1 ADC	I/O I/O I/O O	M	Tristate	—	—	94	133	C6
PE[6]	PCR[70]	AF0 AF1 AF2 AF3	GPIO[70] E0UC[22] CS3_0 MA[1]	SIUL eMIOS_0 DSPI_0 ADC	I/O I/O O O	M	Tristate	—	—	95	139	B5
PE[7]	PCR[71]	AF0 AF1 AF2 AF3	GPIO[71] E0UC[23] CS2_0 MA[0]	SIUL eMIOS_0 DSPI_0 ADC	I/O I/O O O	M	Tristate	—	—	96	140	C4
PE[8]	PCR[72]	AF0 AF1 AF2 AF3	GPIO[72] CAN2TX ¹² E0UC[22] CAN3TX ¹¹	SIUL FlexCAN_2 eMIOS_0 FlexCAN_3	I/O O I/O O	M	Tristate	—	—	9	13	G2
PE[9]	PCR[73]	AF0 AF1 AF2 AF3 — — —	GPIO[73] — E0UC[23] — WKPU[7] ⁴ CAN2RX ¹² CAN3RX ¹¹	SIUL — eMIOS_0 — WKPU FlexCAN_2 FlexCAN_3	I/O — I/O — I I I	S	Tristate	—	—	10	14	G1

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PF[2]	PCR[82]	AF0 AF1 AF2 AF3 —	GPIO[82] E0UC[12] CS0_2 — ANS[10]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O I/O — I	J	Tristate	—	—	—	57	T10
PF[3]	PCR[83]	AF0 AF1 AF2 AF3 —	GPIO[83] E0UC[13] CS1_2 — ANS[11]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	58	R10
PF[4]	PCR[84]	AF0 AF1 AF2 AF3 —	GPIO[84] E0UC[14] CS2_2 — ANS[12]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	59	N11
PF[5]	PCR[85]	AF0 AF1 AF2 AF3 —	GPIO[85] E0UC[22] CS3_2 — ANS[13]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	60	P11
PF[6]	PCR[86]	AF0 AF1 AF2 AF3 —	GPIO[86] E0UC[23] — — ANS[14]	SIUL eMIOS_0 — — ADC	I/O I/O — — I	J	Tristate	—	—	—	61	T11
PF[7]	PCR[87]	AF0 AF1 AF2 AF3 —	GPIO[87] — — — ANS[15]	SIUL — — — ADC	I/O — — — I	J	Tristate	—	—	—	62	R11
PF[8]	PCR[88]	AF0 AF1 AF2 AF3	GPIO[88] CAN3TX ¹⁴ CS4_0 CAN2TX ¹⁵	SIUL FlexCAN_3 DSPI_0 FlexCAN_2	I/O O O O	M	Tristate	—	—	—	34	P1
PF[9]	PCR[89]	AF0 AF1 AF2 AF3 — —	GPIO[89] — CS5_0 — CAN2RX ¹⁵ CAN3RX ¹⁴	SIUL — DSPI_0 — FlexCAN_2 FlexCAN_3	I/O — O — I I	S	Tristate	—	—	—	33	N2

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PG[2]	PCR[98]	AF0 AF1 AF2 AF3	GPIO[98] E1UC[11] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	8	E4
PG[3]	PCR[99]	AF0 AF1 AF2 AF3 —	GPIO[99] E1UC[12] — — WKPU[17] ⁴	SIUL eMIOS_1 — — WKPU	I/O I/O — — I	S	Tristate	—	—	—	7	E3
PG[4]	PCR[100]	AF0 AF1 AF2 AF3	GPIO[100] E1UC[13] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	6	E1
PG[5]	PCR[101]	AF0 AF1 AF2 AF3 —	GPIO[101] E1UC[14] — — WKPU[18] ⁴	SIUL eMIOS_1 — — WKPU	I/O I/O — — I	S	Tristate	—	—	—	5	E2
PG[6]	PCR[102]	AF0 AF1 AF2 AF3	GPIO[102] E1UC[15] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	30	M2
PG[7]	PCR[103]	AF0 AF1 AF2 AF3	GPIO[103] E1UC[16] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	29	M1
PG[8]	PCR[104]	AF0 AF1 AF2 AF3 —	GPIO[104] E1UC[17] — CS0_2 EIRQ[15]	SIUL eMIOS_1 — DSPI_2 SIUL	I/O I/O — I/O I	S	Tristate	—	—	—	26	L2
PG[9]	PCR[105]	AF0 AF1 AF2 AF3	GPIO[105] E1UC[18] — SCK_2	SIUL eMIOS_1 — DSPI_2	I/O I/O — I/O	S	Tristate	—	—	—	25	L1
PG[10]	PCR[106]	AF0 AF1 AF2 AF3	GPIO[106] E0UC[24] — —	SIUL eMIOS_0 — —	I/O I/O — —	S	Tristate	—	—	—	114	D13

3.15.3 I/O output DC characteristics

The following tables provide DC characteristics for bidirectional pads:

- Table 17 provides weak pull figures. Both pull-up and pull-down resistances are supported.
- Table 18 provides output driver characteristics for I/O pads when in SLOW configuration.
- Table 19 provides output driver characteristics for I/O pads when in MEDIUM configuration.
- Table 20 provides output driver characteristics for I/O pads when in FAST configuration.

Table 17. I/O pull-up/pull-down DC electrical characteristics

Symbol		C	Parameter	Conditions ¹		Value			Unit
						Min	Typ	Max	
I _{WPUL}	CC	P	Weak pull-up current absolute value	V _{IN} = V _{IL} , V _{DD} = 5.0 V ± 10%	PAD3V5V = 0	10	—	150	μA
		PAD3V5V = 1 ²			10	—	250		
		P		V _{IN} = V _{IL} , V _{DD} = 3.3 V ± 10%	PAD3V5V = 1	10	—	150	
I _{WPD}	CC	P	Weak pull-down current absolute value	V _{IN} = V _{IH} , V _{DD} = 5.0 V ± 10%	PAD3V5V = 0	10	—	150	μA
		PAD3V5V = 1			10	—	250		
		P		V _{IN} = V _{IH} , V _{DD} = 3.3 V ± 10%	PAD3V5V = 1	10	—	150	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 125 °C, unless otherwise specified.

² The configuration PAD3V5 = 1 when V_{DD} = 5 V is only a transient configuration during power-up. All pads but RESET and Nexus output (MDOx, EVTO, MCKO) are configured in input or in high impedance state.

Table 18. SLOW configuration output buffer electrical characteristics

Symbol	C	Parameter		Conditions ¹	Value			Unit
					Min	Typ	Max	
V _{OH}	CC	P	Output high level SLOW configuration	Push Pull I _{OH} = -2 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	0.8V _{DD}	—	—	V
		C		I _{OH} = -2 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ²	0.8V _{DD}	—	—	
		C		I _{OH} = -1 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	V _{DD} -0.8	—	—	
V _{OL}	CC	P	Output low level SLOW configuration	Push Pull I _{OL} = 2 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	—	—	0.1V _{DD}	V
		C		I _{OL} = 2 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ²	—	—	0.1V _{DD}	
		C		I _{OL} = 1 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	—	—	0.5	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 125 °C, unless otherwise specified

² The configuration PAD3V5 = 1 when V_{DD} = 5 V is only a transient configuration during power-up. All pads but RESET and Nexus output (MDOx, EVTO, MCKO) are configured in input or in high impedance state.

Table 23. I/O consumption (continued)

Symbol	C	D	Parameter	Conditions ¹		Value			Unit
						Min	Typ	Max	
I _{RMSMED}	CC	D	Root mean square I/O current for MEDIUM configuration	C _L = 25 pF, 13 MHz	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	6.6	mA
				C _L = 25 pF, 40 MHz		—	—	13.4	
				C _L = 100 pF, 13 MHz		—	—	18.3	
				C _L = 25 pF, 13 MHz	V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	5	
				C _L = 25 pF, 40 MHz		—	—	8.5	
				C _L = 100 pF, 13 MHz		—	—	11	
I _{RMSFST}	CC	D	Root mean square I/O current for FAST configuration	C _L = 25 pF, 40 MHz	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	22	mA
				C _L = 25 pF, 64 MHz		—	—	33	
				C _L = 100 pF, 40 MHz		—	—	56	
				C _L = 25 pF, 40 MHz	V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	14	
				C _L = 25 pF, 64 MHz		—	—	20	
				C _L = 100 pF, 40 MHz		—	—	35	
I _{AVGSEG}	SR	D	Sum of all the static I/O current within a supply segment	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0		—	—	70	mA
				V _{DD} = 3.3 V ± 10%, PAD3V5V = 1		—	—	65	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 125 °C, unless otherwise specified

² Stated maximum values represent peak consumption that lasts only a few ns during I/O transition.

Table 24 provides the weight of concurrent switching I/Os.

Due to the dynamic current limitations, the sum of the weight of concurrent switching I/Os on a single segment must not exceed 100% to ensure device functionality.

Table 24. I/O weight¹

Supply segment			Pad	144/100 LQFP				64 LQFP			
				Weight 5 V		Weight 3.3 V		Weight 5 V		Weight 3.3 V	
144 LQFP	100 LQFP	64 LQFP ²		SRC ³ = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1
4	4	3	PB[3]	10%	—	12%	—	10%	—	12%	—
			PC[9]	10%	—	12%	—	10%	—	12%	—
		—	PC[14]	9%	—	11%	—	—	—	—	—
		—	PC[15]	9%	13%	11%	12%	—	—	—	—
	—	—	PG[5]	9%	—	11%	—	—	—	—	—
	—	—	PG[4]	9%	12%	10%	11%	—	—	—	—
	—	—	PG[3]	9%	—	10%	—	—	—	—	—

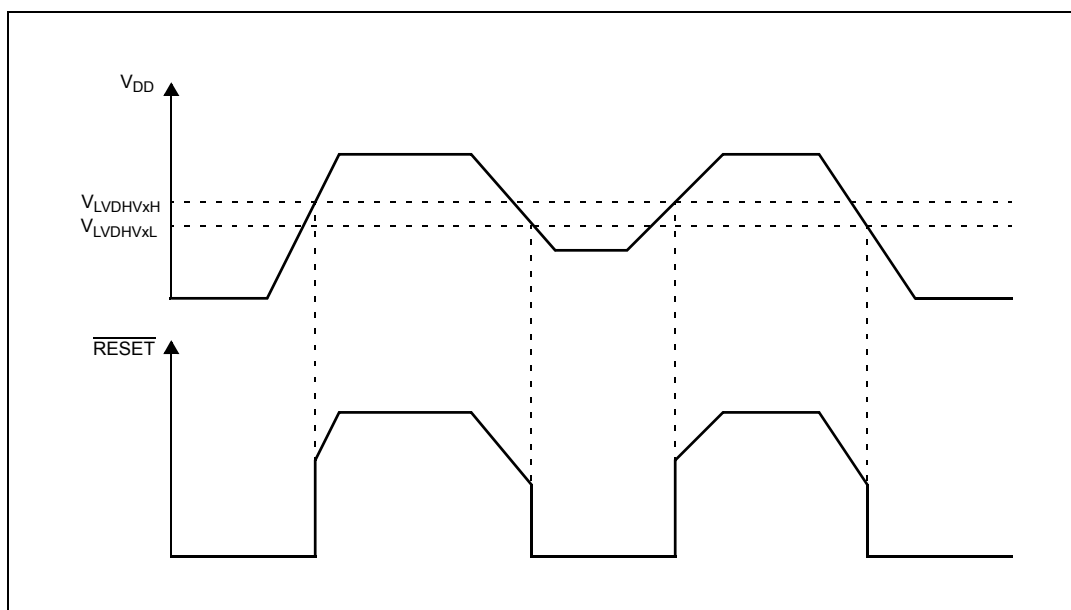


Figure 13. Low voltage detector vs reset

Table 27. Low voltage detector electrical characteristics

Symbol		C	Parameter	Conditions ¹	Value			Unit
					Min	Typ	Max	
V _{PORUP}	SR	P	Supply for functional POR module	—	1.0	—	5.5	V
V _{PORH}	CC	P	Power-on reset threshold	T _A = 25 °C, after trimming	1.5	—	2.6	
		T		—	1.5	—	2.6	
V _{LVDHV3H}	CC	T	LVDHV3 low voltage detector high threshold	—	—	—	2.95	
V _{LVDHV3L}	CC	P	LVDHV3 low voltage detector low threshold		2.6	—	2.9	
V _{LVDHV5H}	CC	T	LVDHV5 low voltage detector high threshold		—	—	4.5	
V _{LVDHV5L}	CC	P	LVDHV5 low voltage detector low threshold		3.8	—	4.4	
V _{LVDLVCORL}	CC	P	LVDLVCOR low voltage detector low threshold		1.08	—	1.16	
V _{LVDLVBKPL}	CC	P	LVDLVBKP low voltage detector low threshold		1.08	—	1.16	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 125 °C, unless otherwise specified

3.18 Power consumption

Table 28 provides DC electrical characteristics for significant application modes. These values are indicative values; actual consumption depends on the application.

Table 32. Flash memory power supply DC electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value			Unit
				Min	Typ	Max	
I _{FLPW}	CC	D	Sum of the current consumption on VDD_HV and VDD_BV	—	—	900	μA
			During data flash memory low-power mode			900	
I _{FPWD}	CC	D	Sum of the current consumption on VDD_HV and VDD_BV	—	—	150	μA
			During data flash memory power-down mode			150	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

² This value is only relative to the actual duration of the read cycle

³ f_{CPU} 64 MHz can be achieved only at up to 105 °C

3.19.3 Start-up/Switch-off timings

Table 33. Start-up time/Switch-off time

Symbol	C	Parameter	Conditions ¹	Value			Unit
				Min	Typ	Max	
T _{FLARSTEXT}	CC	T	Delay for Flash module to exit reset mode	Code Flash	—	—	μs
			Data Flash	—	—	125	
T _{FLALPEXIT}	CC	T	Delay for Flash module to exit low-power mode	Code Flash	—	—	0.5
			Data Flash	—	—	0.5	
T _{FLAPDEXIT}	CC	T	Delay for Flash module to exit power-down mode	Code Flash	—	—	30
			Data Flash	—	—	30	
T _{FLALPENTRY}	CC	T	Delay for Flash module to enter low-power mode	Code Flash	—	—	0.5
			Data Flash	—	—	0.5	
T _{FLAPDENTRY}	CC	T	Delay for Flash module to enter power-down mode	Code Flash	—	—	1.5
			Data Flash	—	—	1.5	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

3.20 Electromagnetic compatibility (EMC) characteristics

Susceptibility tests are performed on a sample basis during product characterization.

3.20.1 Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Package pinouts and signal descriptions

possible, ideally infinite. This capacitor contributes to attenuating the noise present on the input pin; furthermore, it sources charge during the sampling phase, when the analog signal source is a high-impedance source.

A real filter can typically be obtained by using a series resistance with a capacitor on the input pin (simple RC filter). The RC filtering may be limited according to the value of source impedance of the transducer or circuit supplying the analog signal to be measured. The filter at the input pins must be designed taking into account the dynamic characteristics of the input signal (bandwidth) and the equivalent input impedance of the ADC itself.

In fact a current sink contributor is represented by the charge sharing effects with the sampling capacitance: being C_S and C_{P2} substantially two switched capacitances, with a frequency equal to the conversion rate of the ADC, it can be seen as a resistive path to ground. For instance, assuming a conversion rate of 1 MHz, with $C_S + C_{P2}$ equal to 3 pF, a resistance of 330 kΩ is obtained ($R_{EQ} = 1 / (f_c \times (C_S + C_{P2}))$), where f_c represents the conversion rate at the considered channel). To minimize the error induced by the voltage partitioning between this resistance (sampled voltage on $C_S + C_{P2}$) and the sum of $R_S + R_F$, the external circuit must be designed to respect the Equation 4:

Eqn. 4

$$V_A \cdot \frac{R_S + R_F}{R_{EQ}} < \frac{1}{2} \text{ LSB}$$

Equation 4 generates a constraint for external network design, in particular on a resistive path.

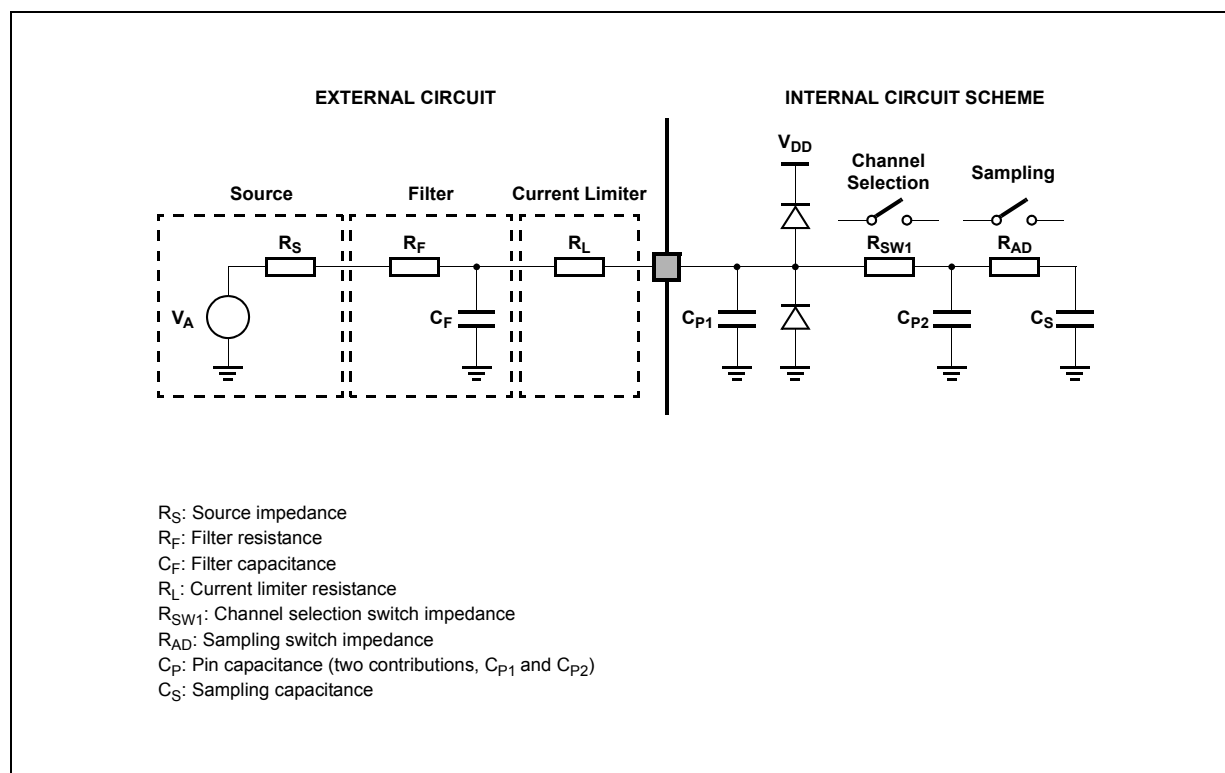


Figure 20. Input equivalent circuit (precise channels)

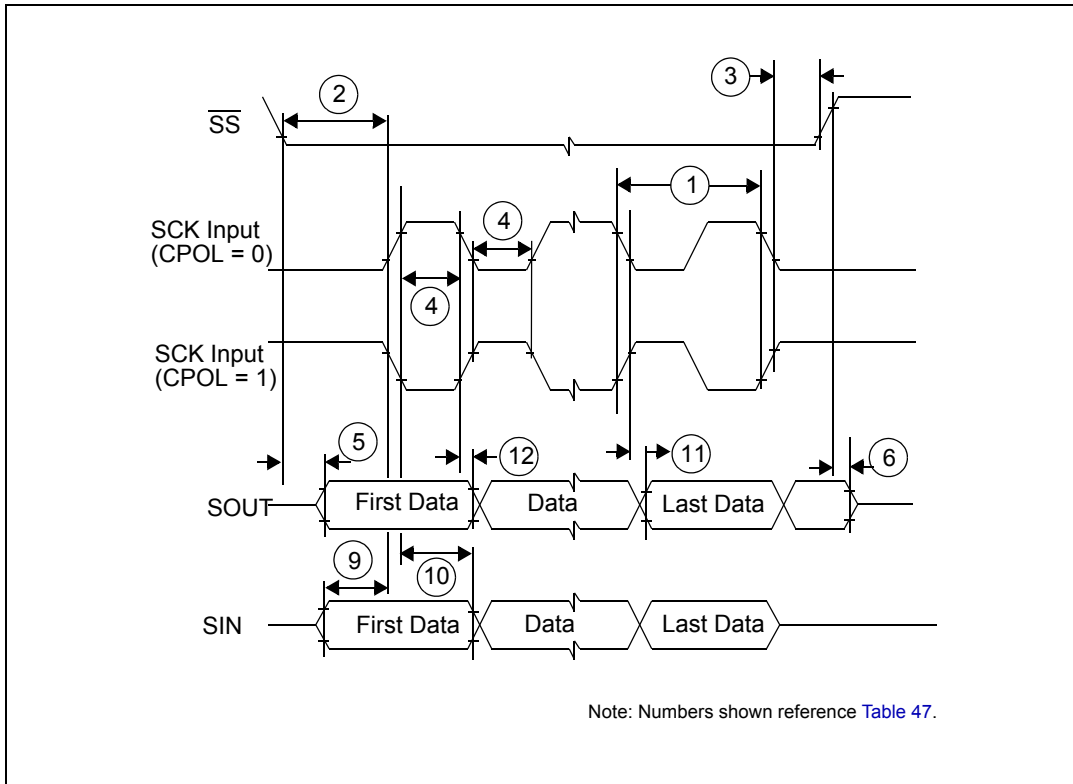


Figure 26. DSPI classic SPI timing – slave, CPHA = 0

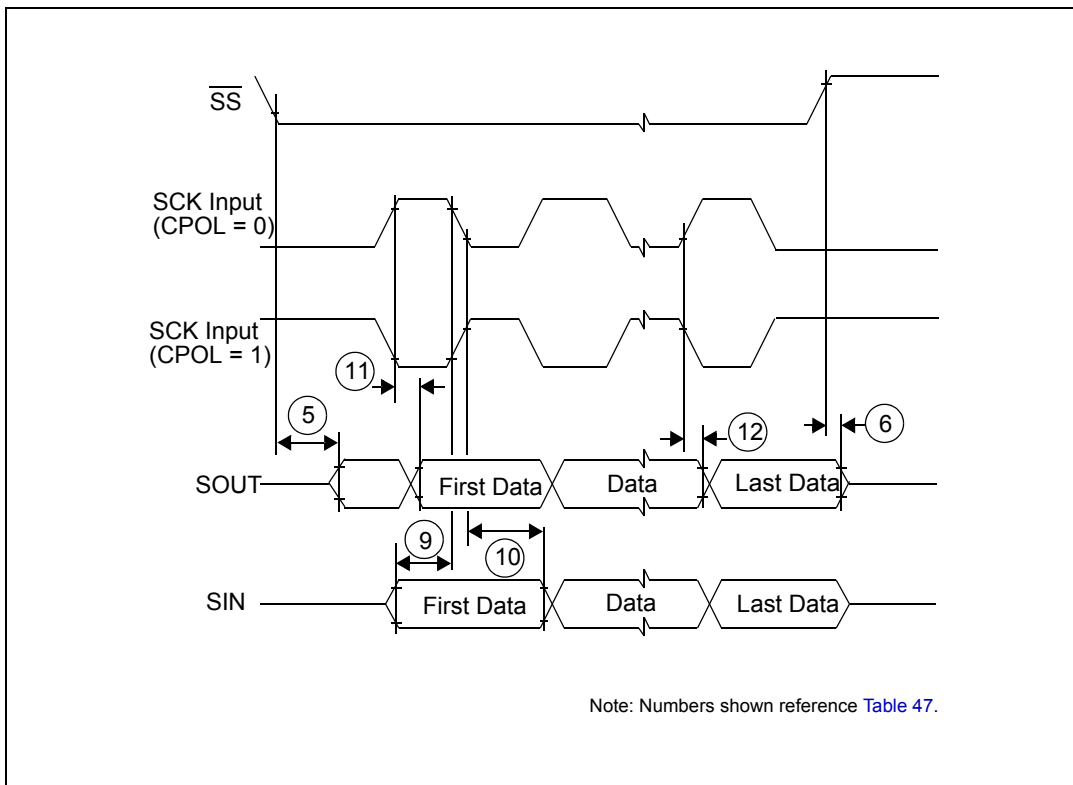


Figure 27. DSPI classic SPI timing – slave, CPHA = 1

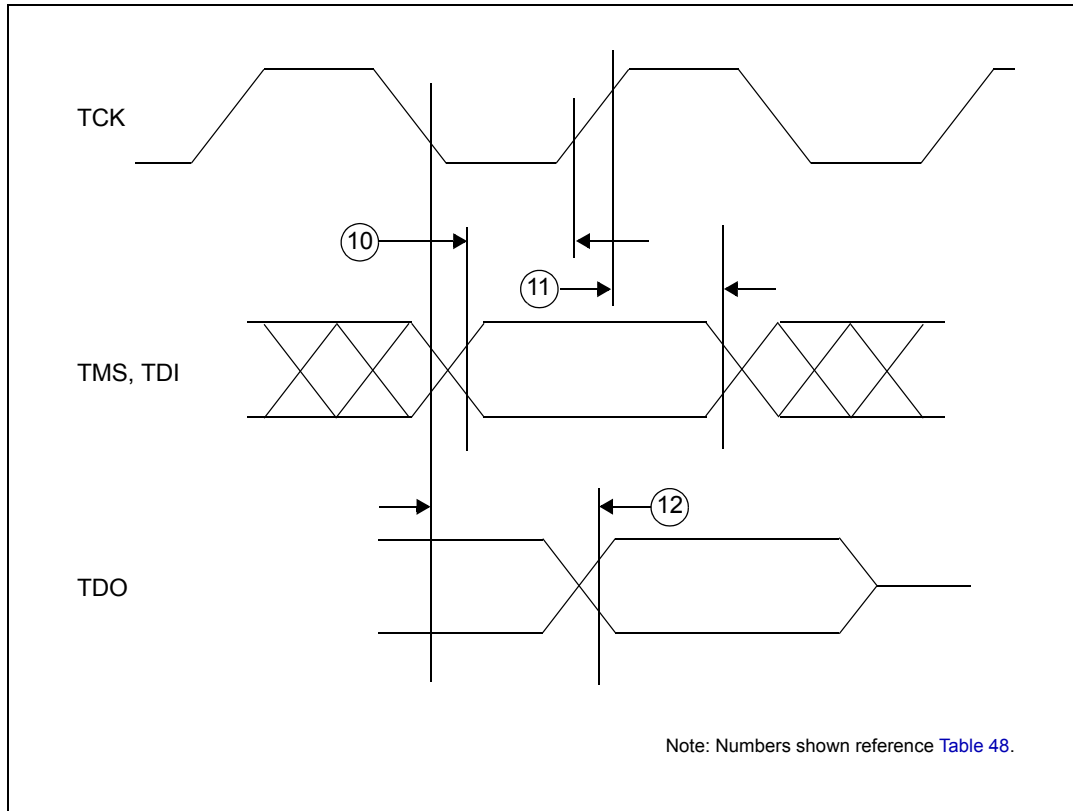


Figure 33. Nexus TDI, TMS, TDO timing

3.27.4 JTAG characteristics

Table 49. JTAG characteristics

No.	Symbol	C	Parameter	Value			Unit
				Min	Typ	Max	
1	t_{JCYC}	CC	D TCK cycle time	64	—	—	ns
2	t_{TDIS}	CC	D TDI setup time	15	—	—	ns
3	t_{TDIH}	CC	D TDI hold time	5	—	—	ns
4	t_{TMSS}	CC	D TMS setup time	15	—	—	ns
5	t_{TMSh}	CC	D TMS hold time	5	—	—	ns
6	t_{TDOV}	CC	D TCK low to TDO valid	—	—	33	ns
7	t_{TDOI}	CC	D TCK low to TDO invalid	6	—	—	ns

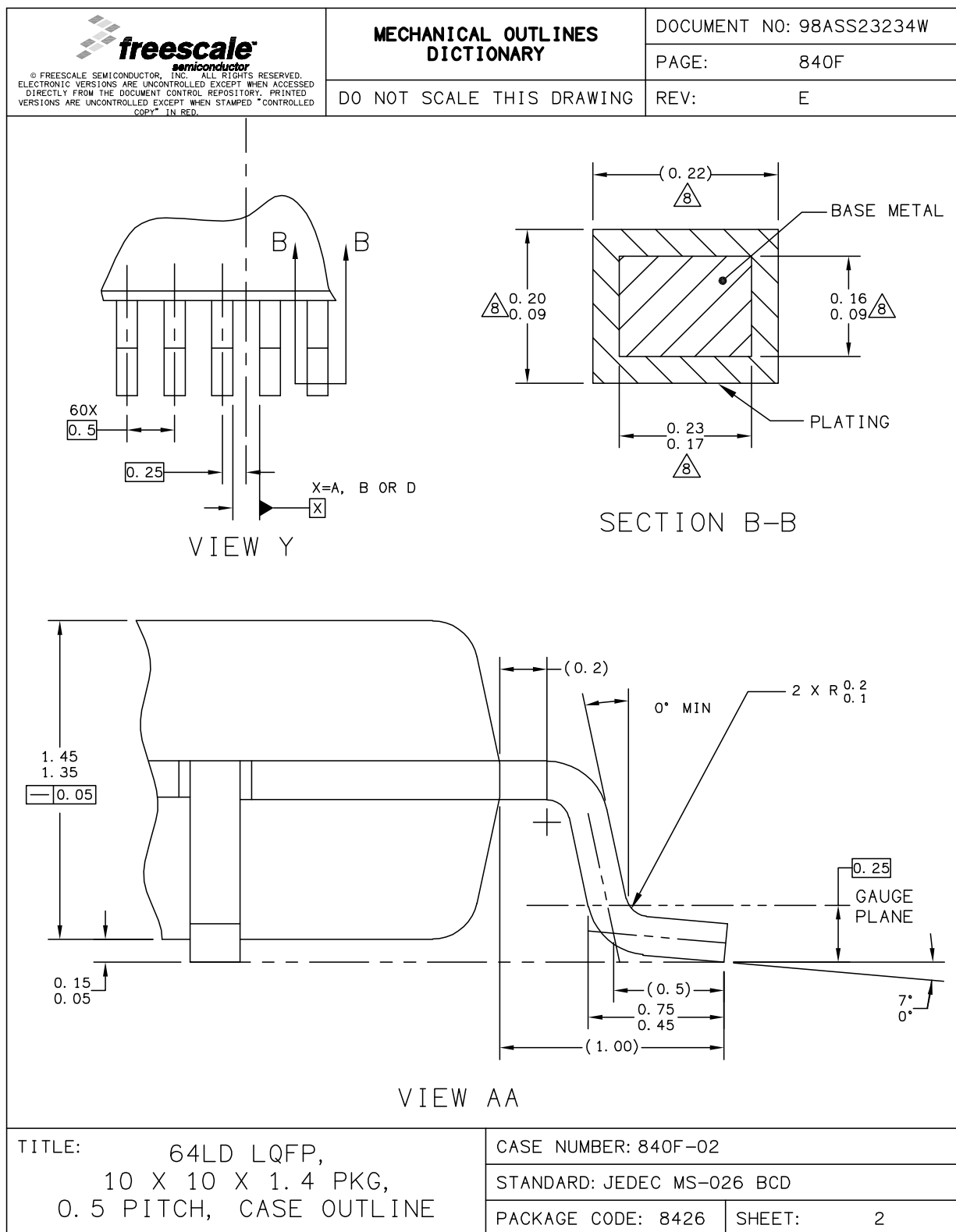


Figure 36. 64 LQFP package mechanical drawing (2 of 3)

Table 50. Revision history (continued)

Revision	Date	Description of Changes
4	06-Aug-2009	Updated Figure 6 Table 12 • V_{DD_ADC}: changed min value for “relative to V_{DD}” condition • V_{IN}: changed min value for “relative to V_{DD}” condition • I_{CORELV}: added new row Table 14 • $T_{A\ C-Grade\ Part}$, $T_{J\ C-Grade\ Part}$, $T_{A\ V-Grade\ Part}$, $T_{J\ V-Grade\ Part}$, $T_{A\ M-Grade\ Part}$, $T_{J\ M-Grade\ Part}$: added new rows • Changed capacitance value in footnote Table 21 • MEDIUM configuration: added condition for $PAD3V5V = 0$ Updated Figure 10 Table 26 • C_{DEC1}: changed min value • I_{MREG}: changed max value • I_{DD_BV}: added max value footnote Table 27 • $V_{LVDHV3H}$: changed max value • $V_{LVDHV3L}$: added max value • $V_{LVDHV5H}$: changed max value • $V_{LVDHV5L}$: added max value Updated Table 28 Table 30 • Retention: deleted min value footnote for “Blocks with 100,000 P/E cycles” Table 38 • I_{FXOSC}: added typ value Table 40 • V_{SXOSC}: changed typ value • $T_{SXOSCSU}$: added max value footnote Table 41 • Δt_{LTJIT}: added max value Updated Figure 38

Table 50. Revision history (continued)

Revision	Date	Description of Changes
6	15-Mar-2010	In the "Introduction" section, relocated a note. In the "MPC5604B/C device comparison" table, added footnote regarding SCI and CAN. In the "Absolute maximum ratings" table, removed the min value of V_{IN} relative to V_{DD}. In the "Recommended operating conditions (3.3 V)" table: • T_A C-Grade Part, T_J C-Grade Part, T_A V-Grade Part, T_J V-Grade Part, T_A M-Grade Part, T_J M-Grade Part: added new rows. • T_{VDD}: made single row. In the "LQFP thermal characteristics" table, added more rows. Removed "208 MAPBGA thermal characteristics" table. In the "I/O consumption" table: • Removed I_{DYNSEG} row. • Added "I/O weight" table. In the "Voltage regulator electrical characteristics" table: • Updated the values. • Removed $I_{VREGREF}$ and $I_{VREDLVD12}$. • Added a note about I_{DD_BC}. In the "Low voltage monitor electrical characteristics" table: • Updated V_{PORH} values. • Updated $V_{LVDLVCORL}$ value. Entirely updated the "Low voltage power domain electrical characteristics" table. In the "Program and erase specifications" table, inserted T_{eslat} row. Entirely updated the "Flash power supply DC electrical characteristics" table. Entirely updated the "Start-up time/Switch-off time" table. In the "Crystal oscillator and resonator connection scheme" figure, relocated a note. In the "Slow external crystal oscillator (32 kHz) electrical characteristics" table: • Removed g_{mSXOSC} row. • Inserted values of $I_{SXOSCBIAS}$. Entirely updated the "Fast internal RC oscillator (16 MHz) electrical characteristics" table. In the "ADC conversion characteristics" table: updated the description of the conditions of t_{ADC_PU} and t_{ADC_S}. Entirely updated the "DSPI characteristics" table. In the "Orderable part number summary" table, modified some orderable part number. Updated the "Commercial product code structure" figure. Removed the note about the condition from "Flash read access timing" table Removed the notes that assert the values need to be confirmed before validation Exchanged the order of "LQFP 100-pin configuration" and "LQFP 144-pin configuration" Exchanged the order of "LQFP 100-pin package mechanical drawing" and "LQFP 144-pin package mechanical drawing"